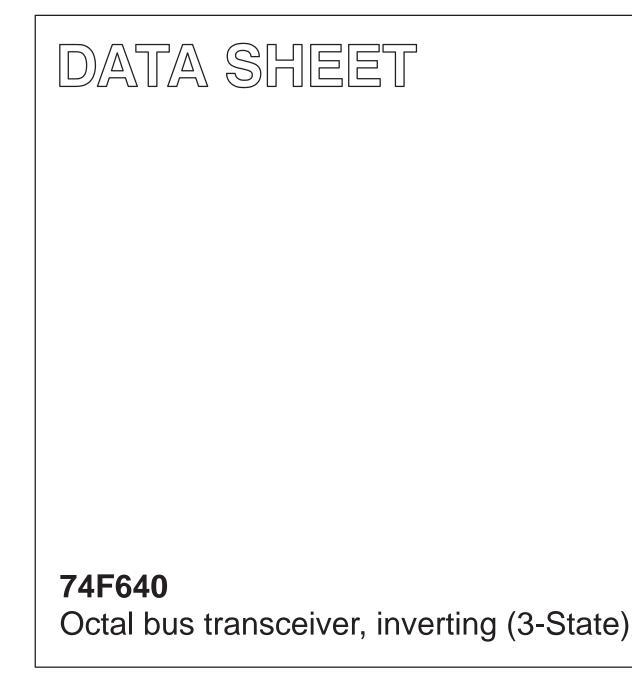
## INTEGRATED CIRCUITS



Product specification

1989 Nov 27

IC15 Data Handbook



HILIPS

Philips Semiconductors

74F640

### **FEATURES**

- High-impedance NPN base inputs for reduced loading (70μA in High and Low states)
- Ideal for applications which require high-output drive and minimal bus loading
- Inverting version of 74F245
- Octal bidirectional bus interface
- 3-State outputs sink 64mA and source 15mA

### DESCRIPTION

The 74F640 is an octal transceiver featuring inverting 3-State bus compatible outputs in both transmit and receive directions. The B port outputs are capable of sinking 64mA and sourcing 15mA, providing very good capacitive drive characteristics. The device features an Output Enable ( $\overline{OE}$ ) input for easy cascading and Transmit/Receiver (T/ $\overline{R}$ ) input for direction control. The 3-State outputs, B0–B7, have been designed to prevent output bus loading if the power is removed from the device.

#### **PIN CONFIGURATION**

T/R 1	
A0 2	19 OE
A1 3	18 B0
A2 4	17 B1
A3 5	16 B2
A4 6	15 B3
A5 7	14 B4
A6 8	13 B5
A7 9	12 B6
GND 10	11 B7
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TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F640	3.5ns	78mA

### ORDERING INFORMATION

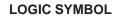
DESCRIPTION	$\begin{array}{l} \mbox{COMMERCIAL RANGE} \\ \mbox{V}_{CC} = 5V \pm 10\%, \\ \mbox{T}_{amb} = 0^{\circ} \mbox{C to } + 70^{\circ} \mbox{C} \end{array}$	PKG DWG #
20-pin plastic DIP	N74F640N	SOT146-1
20-pin plastic SOL	N74F640D	SOT163-1

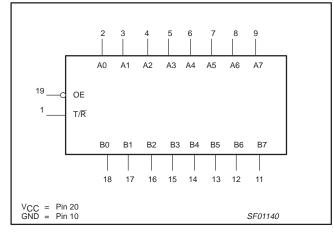
### INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

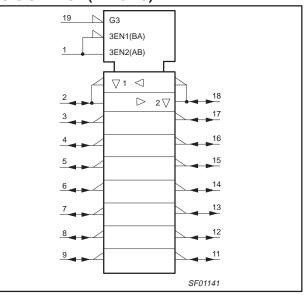
PINS	DESCRIPTION	74F(U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
A0 - A7, B0 - B7	Data inputs	3.5/0.115	70μΑ/70μΑ
ŌĒ	Output Enable input (active Low)	2.0/0.067	40μΑ/40μΑ
T/R	Transmit/Receive input	2.0/0.067	40μΑ/40μΑ
A0 - A7	A port outputs	150/40	3.0mA/24mA
B0 - B7	B port outputs	750/106.7	15mA/64mA

**NOTE:** One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

74F640







### **FUNCTION TABLE**

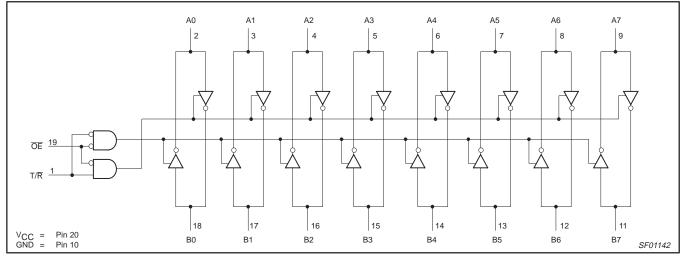
INPU	ITS	OUTPUTS
ŌĒ	T/R	0012013
L	L	Bus B data to Bus A
L	н	Bus A data to Bus $\overline{B}$
н	Х	Z

High voltage level Low voltage level H =

L =

X = Don't care Z = High impedance "off" state

### LOGIC DIAGRAM



### LOGIC SYMBOL (IEEE/IEC)

74F640

### **ABSOLUTE MAXIMUM RATINGS**

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V <sub>CC</sub>	Supply voltage		-0.5 to +7.0	V
V <sub>IN</sub>	Input voltage		-0.5 to +7.0	V
I <sub>IN</sub>	Input current		-30 to +5	mA
V <sub>OUT</sub>	Voltage applied to output in High output state		–0.5 to +V <sub>CC</sub>	V
		A0–A7	48	mA
IOUT	Current applied to output in Low output state	B0–B7	128	mA
T <sub>amb</sub>	Operating free-air temperature range		0 to +70	°C
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

### **RECOMMENDED OPERATING CONDITIONS**

CYMDOL	DADAN			LINUT		
SYMBOL	PARAM	PARAMETER				UNIT
V <sub>CC</sub>	Supply voltage		4.5	5.0	5.5	V
V <sub>IH</sub>	High-level input voltage		2.0			V
V <sub>IL</sub>	Low-level input voltage			0.8	V	
I <sub>IK</sub>	Input clamp current				-18	mA
		A0–A7			-3	mA
ЮН	High-level output current	B0–B7			-15	mA
1		A0–A7	1		24	mA
IOL	Low-level output current	B0–B7			64	mA
T <sub>amb</sub>	Operating free-air temperature range	0		70	°C	

### DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

						LIMITS			
SYMBOL	PARAMETER		TEST	MIN	TYP NO TAG	МАХ	UNIT		
		A0-A7		1 0m1	±10%V <sub>CC</sub>	2.4			V
M		B0–B7	$V_{CC} = MIN,$ $V_{II} = MAX,$	I <sub>OH</sub> = -3mA	±5%V <sub>CC</sub>	2.7	3.3		V
V <sub>OH</sub>	High-level output voltage	B0-B7	$V_{IH} = MIN$	I <sub>OH</sub> = -15mA	±10%V <sub>CC</sub>	2.0			V
		В0-В7		$I_{OH} = -15IIIA$	±5%V <sub>CC</sub>	2.0			V
		A0-A7		I <sub>OL</sub> = 24mA	$\pm 10\% V_{CC}$		0.35	0.50	V
V <sub>OL</sub>	Low-level output voltage	AU-A7	$V_{CC} = MIN,$ $V_{IL} = MAX,$	$I_{OL} = 2411A$	$\pm 5\% V_{CC}$		0.35	0.50	V
VOL	Low-level output voltage	B0–B7	$V_{IH} = MIN,$	I <sub>OL</sub> = MAX	$\pm 10\% V_{CC}$			0.55	V
		B0-B7		OL = MAX	$\pm 5\% V_{CC}$		0.42	0.55	V
V <sub>IK</sub>	Input clamp voltage		$V_{CC} = MIN, I_{I}$	$V_{CC} = MIN, I_I = I_{IK}$			-0.73	-1.2	V
կ	Input current at maximum		$V_{CC} = 0.0V, V_{I} = 7.0V$					100	μA
'I	input voltage	A0–A7, B0–B7	V <sub>CC</sub> = 5.5V, V	<sub>I</sub> = 5.5V				1.0	mA
I <sub>IH</sub>	High-level input current	OE, T/R	V <sub>CC</sub> = MAX, V	′ <sub>l</sub> = 2.7V				40	μΑ
IIL	Low-level input current	only	V <sub>CC</sub> = MAX, V	′ <sub>I</sub> = 0.5V				-40	μA
I <sub>OZH</sub> +I <sub>IH</sub>	Off-state output current, High level of voltage applied		V <sub>CC</sub> = MAX, V	′ <sub>I</sub> = 2.7V				70	μA
I <sub>OZL</sub> +I <sub>IL</sub>	Off-state output current, Low level of voltage applied		V <sub>CC</sub> = MAX, V	′ <sub>I</sub> = 0.5V				-70	μΑ
1	Short-circuit output cur-	A0–A7				-60		-150	mA
los rent <sup>NO TAG</sup>		B0–B7	V <sub>CC</sub> = MAX			-100		-225	μΑ
		I <sub>ССН</sub>		$\frac{T/\overline{R}}{OE} = An = 4.5V,$			66	85	mA
I <sub>CC</sub>	Supply current (total)	I <sub>CCL</sub>	V <sub>CC</sub> = MAX	$T/\overline{R} = Bn = \overline{OE} = GND$			91	120	mA
		I <sub>CCZ</sub>	]	$\frac{T/\overline{R} = Bn = GND,}{\overline{OE} = 4.5V}$			78	102	mA

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

 All typical values are at V<sub>CC</sub> = 5V, T<sub>amb</sub> = 25°C.
Not more than one output should be shorted at a time. For testing I<sub>OS</sub>, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, IOS tests should be performed last.

74F640

### 74F640

### AC ELECTRICAL CHARACTERISTICS

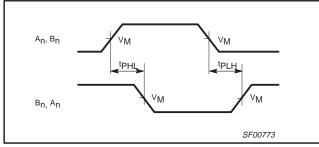
					LIM	ITS		
SYMBOL	PARAMETER	TEST CONDITION	Ta	/ <sub>CC</sub> = +5\ <sub>mb</sub> = +25 0pF, R <sub>L</sub> =	°C	V <sub>CC</sub> = +5 T <sub>amb</sub> = 0°C C <sub>L</sub> = 50pF,	C to +70°C	UNIT
	Ι Γ		MIN	ТҮР	MAX	MIN	MAX	
t <sub>PLH</sub>	Propagation delay	Waveform	2.0	4.5	7.0	2.0	8.0	ns
t <sub>PHL</sub>	An to Bn, Bn to An	NO TAG	1.0	2.5	5.0	1.0	5.5	
t <sub>PZH</sub>	Output Enable time	Waveform 3	5.5	6.5	10.5	5.0	12.0	ns
t <sub>PZL</sub>	to High or Low level	Waveform 2	5.5	7.0	10.5	5.0	11.0	
t <sub>PHZ</sub>	Output Disable time	Waveform 3	2.0	3.5	6.5	1.5	8.0	ns
t <sub>PLZ</sub>	from High or Low level	Waveform 2	2.0	4.5	7.0	2.0	7.5	

### 74F640

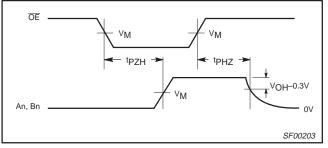
SF00128

### AC WAVEFORMS

For all waveforms,  $V_M = 1.5V$ .

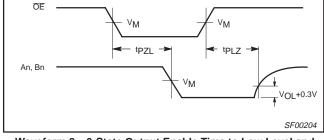


Waveform 1. Propagation Delay for Inverting Outputs

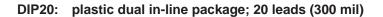


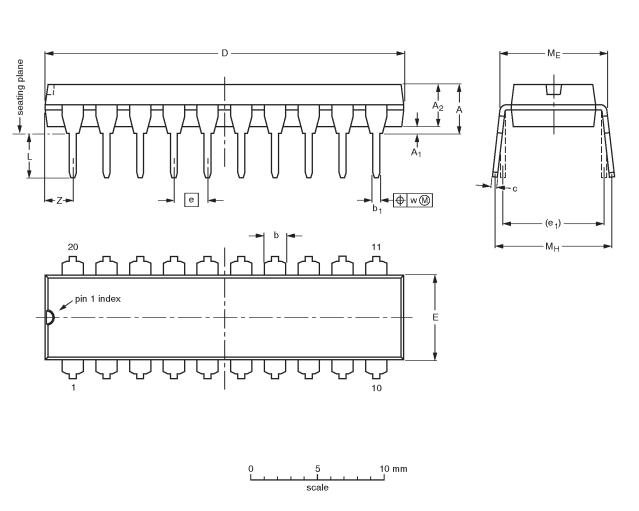
Waveform 3. 3-State Output Enable Time to High Level and Output Disable Time from High Level

#### **TEST CIRCUIT AND WAVEFORMS** VCC AMP (V) -0 7.0V 90% 90% NEGATIVE PULSE Rı ٧м ٧N VIN VOUT 10% 10% PULSE GENERATOR D.U.T. $\odot$ 0V - tTHL (tf) tTLH (tr) ξ<sub>RT</sub> ≷ RL CL tTLH (tr) tTHL (tf) AMP (V) 90% 90% POSITIVE PULSE Test Circuit for Open Collector Outputs ٧M ٧м 10% 10% 0V SWITCH POSITION TEST SWITCH **Input Pulse Definition** closed t<sub>PLZ</sub> closed t<sub>PZL</sub> All other open **DEFINITIONS:** Load resistor; $R_L =$ **INPUT PULSE REQUIREMENTS** see AC electrical characteristics for value. family Load capacitance includes jig and probe capacitance; $C_L =$ amplitude VM rep. rate t<sub>TLH</sub> t<sub>THL</sub> tw see AC electrical characteristics for value. $R_T =$ Termination resistance should be equal to ZOUT of 74F 3.0V 1.5V 1MHz 500ns 2.5ns 2.5ns pulse generators.



Waveform 2. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level





#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	с	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

#### Note

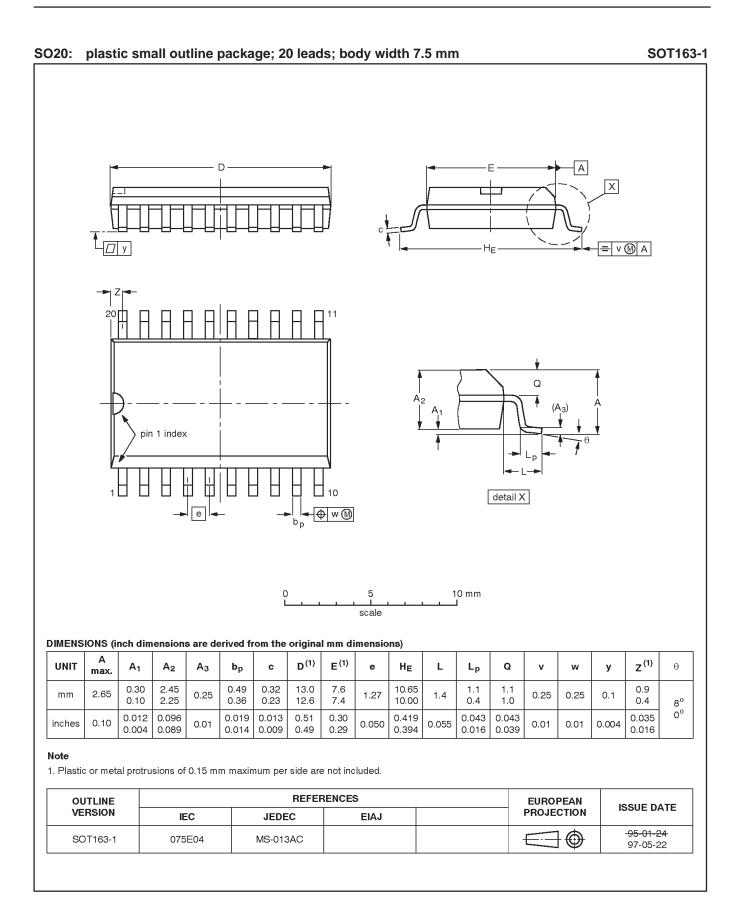
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT146-1			SC603			<del>-92-11-17</del> 95-05-24

# Product specification 74F640

SOT146-1

### 74F640



NOTES

## 74F640

### 74F640

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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